NSN 5962-01-450-6525

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-450-6525

Maximum Power Dissipation Rating:
1.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15s
Features Provided:
Electrostatic sensitive and programmed and ultraviolet erasable and burn in
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Input Circuit Pattern:
15 input
Criticality Code Justification:
Cbbl
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital-programmable read only memory, uv erasable
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
250.00 nanoseconds access
Memory Device Type:
Pal
Special Features:
Altered item make from smd 8202505ya; generic pn 27128 and 27128a and 27c128
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
<u></u>
Demilitarization:
No
Fiig:
A458a0